

Single N-channel MOSFET

ELM14420AA-N

■General description

ELM14420AA-N uses advanced trench technology to provide excellent $R_{ds(on)}$, low gate charge and low gate resistance.

■Features

- $V_{ds}=30V$
- $I_d=13.7A$ ($V_{gs}=10V$)
- $R_{ds(on)} < 10.5m\Omega$ ($V_{gs}=10V$)
- $R_{ds(on)} < 12m\Omega$ ($V_{gs}=4.5V$)

■Maximum absolute ratings

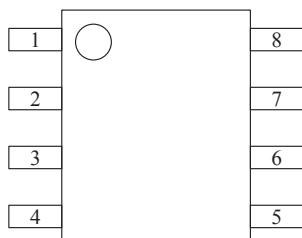
Parameter	Symbol	Limit	Unit	Note
Drain-source voltage	V_{ds}	30	V	
Gate-source voltage	V_{gs}	± 12	V	
Continuous drain current	I_d	13.7	A	1
		9.7		
Pulsed drain current	I_{dm}	60	A	2
Power dissipation	P_d	3.1	W	
		2.0		
Junction and storage temperature range	T_j, T_{stg}	-55 to 150	°C	

■Thermal characteristics

Parameter		Symbol	Typ.	Max.	Unit	Note
Maximum junction-to-ambient	$t \leq 10s$	$R_{\theta ja}$	28	40	°C /W	1
Maximum junction-to-ambient	Steady-state		54	75	°C /W	
Maximum junction-to-lead	Steady-state	$R_{\theta jl}$	21	30	°C /W	3

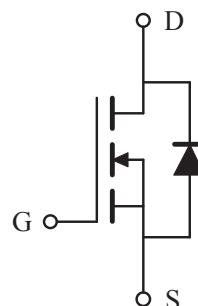
■Pin configuration

SOP-8(TOP VIEW)



Pin No.	Pin name
1	SOURCE
2	SOURCE
3	SOURCE
4	GATE
5	DRAIN
6	DRAIN
7	DRAIN
8	DRAIN

■Circuit



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■Electrical characteristics

$T_a=25^\circ C$

Parameter	Symbol	Condition		Min.	Typ.	Max.	Unit
STATIC PARAMETERS							
Drain-source breakdown voltage	BV_{DSS}	$I_D=250\mu A, V_{GS}=0V$		30			V
Zero gate voltage drain current	Id_{SS}	$V_{DS}=24V, V_{GS}=0V$			0.004	1.000	μA
			$T_j=55^\circ C$			5.000	
Gate-body leakage current	I_{GSS}	$V_{DS}=0V, V_{GS}=\pm 12V$				100	nA
Gate threshold voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$		0.6	1.1	2.0	V
On state drain current	$I_{D(on)}$	$V_{GS}=4.5V, V_{DS}=5V$		40			A
Static drain-source on-resistance	$R_{DS(on)}$	$V_{GS}=10V$			8.3	10.5	$m\Omega$
		$I_D=13.7A$	$T_j=125^\circ C$		12.5	15.0	
		$V_{GS}=4.5V, I_D=12.7A$			9.7	12.0	$m\Omega$
Forward transconductance	G_{FS}	$V_{DS}=5V, I_D=13.7A$		30	37		S
Diode forward voltage	V_{SD}	$I_S=1A, V_{GS}=0V$			0.76	1.00	V
Max. body-diode continuous current	I_S					5	A
DYNAMIC PARAMETERS							
Input capacitance	C_{ISS}	$V_{GS}=0V, V_{DS}=15V, f=1MHz$			3656	4050	pF
Output capacitance	C_{OSS}				256		pF
Reverse transfer capacitance	C_{RSS}				168		pF
Gate resistance	R_g	$V_{GS}=0V, V_{DS}=0V, f=1MHz$			0.86	1.10	Ω
SWITCHING PARAMETERS							
Total gate charge (4.5V)	Q_g	$V_{GS}=10V, V_{DS}=15V, I_D=13.7A$			30.5	36.0	nC
Gate-source charge	Q_{GS}				4.6		nC
Gate-drain charge	Q_{GD}				8.6		nC
Turn-on delay time	$t_{D(on)}$	$V_{GS}=10V, V_{DS}=15V$			5.5	9.0	ns
Turn-on rise time	t_r				3.4	7.0	ns
Turn-off delay time	$t_{D(off)}$		$R_L=1.1\Omega, R_{GEN}=0\Omega$		49.8	75.0	ns
Turn-off fall time	t_f				5.9	11.0	ns
Body diode reverse recovery time	t_{RR}		$I_F=13.7A, dI/dt=100A/\mu s$		22.5	28.0	ns
Body diode reverse recovery charge	Q_{RR}	$I_F=13.7A, dI/dt=100A/\mu s$			12.5	16.0	nC

NOTE :

1. The value of $R_{\theta ja}$ is measured with the device mounted on 1in² FR-4 board of 2oz. Copper, in still air environment with $T_a=25^\circ C$. The value in any given applications depends on the user's specific board design. The current rating is based on the $t \leq 10s$ thermal resistance rating.
2. Repetitive rating, pulse width limited by junction temperature.
3. The $R_{\theta ja}$ is the sum of the thermal impedance from junction to lead $R_{\theta jl}$ and lead to ambient.
4. The static characteristics in Figures 1 to 6 are obtained using 80 μs pulses, duty cycle 0.5%max.
5. These tests are performed with the device mounted on 1in² FR-4 board with 2oz. Copper, in a still air environment with $T_a=25^\circ C$. The SOA curve provides a single pulse rating.



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■ Typical electrical and thermal characteristics

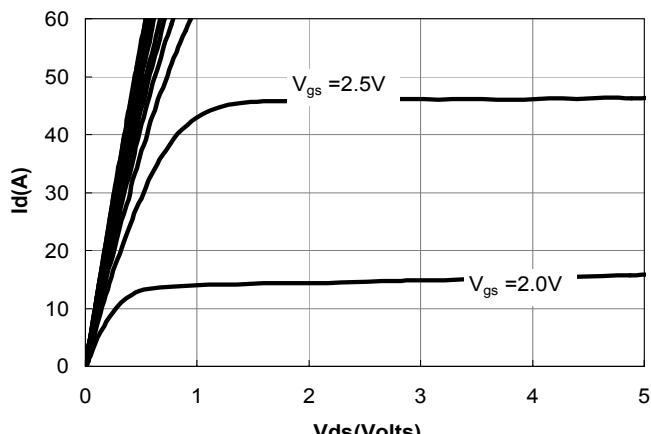


Figure 1: On-Regions Characteristics

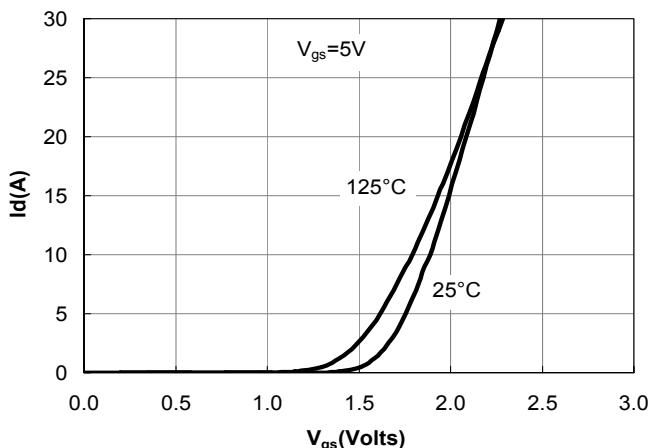


Figure 2: Transfer Characteristics

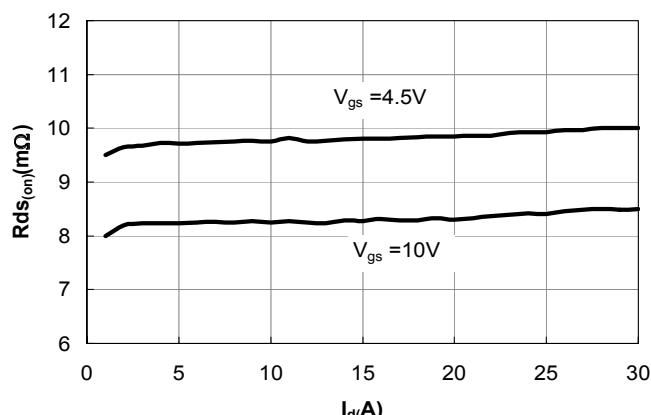


Figure 3: On-Resistance vs. Drain Current and Gate Voltage

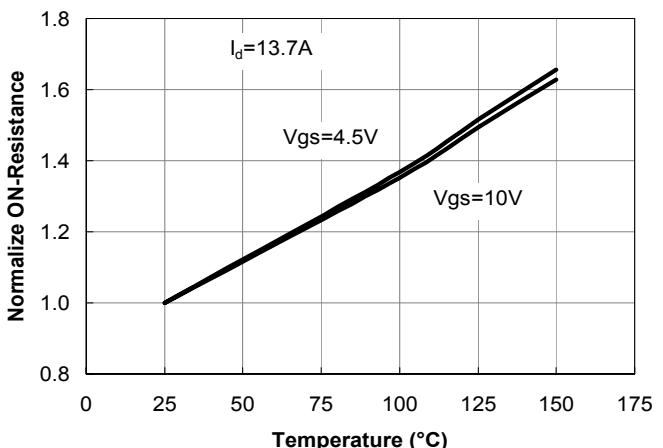


Figure 4: On-Resistance vs. Junction Temperature

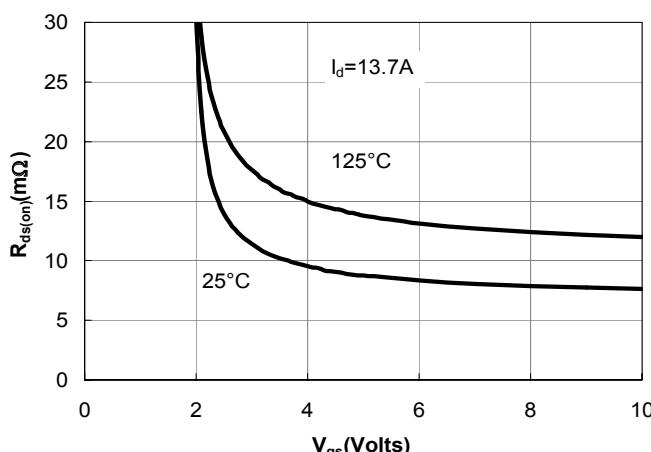


Figure 5: On-Resistance vs. Gate-Source Voltage

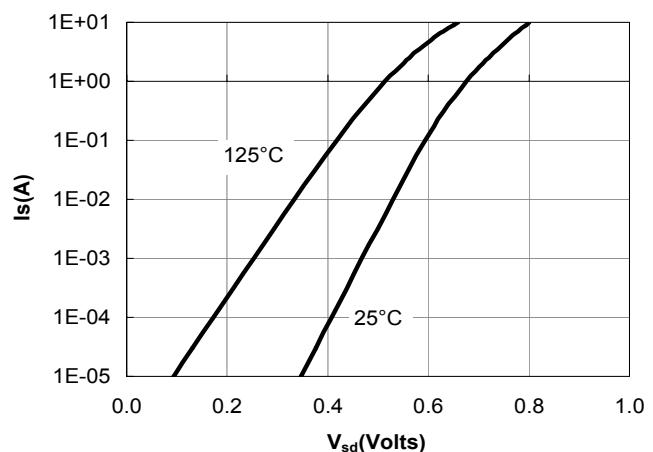


Figure 6: Body-Diode Characteristics

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